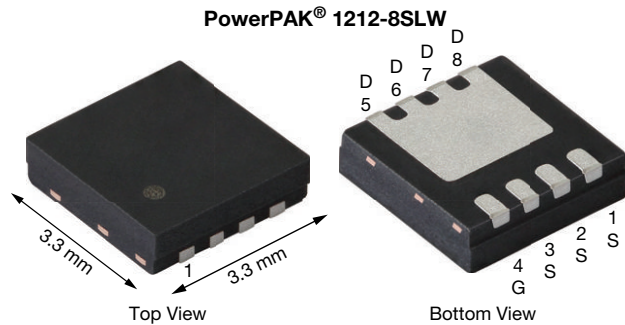


Automotive N-Channel 30 V (D-S) 175 °C MOSFET

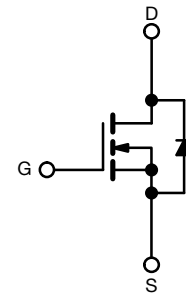


RoHS
COMPLIANT
HALOGEN
FREE



Marking code: Q078

PRODUCT SUMMARY	
V_{DS} (V)	30
$R_{DS(on)}$ (Ω) at $V_{GS} = 10$ V	0.0018
$R_{DS(on)}$ (Ω) at $V_{GS} = 4.5$ V	0.0028
I_D (A) ^e	192
Configuration	Single



N-Channel MOSFET

ORDERING INFORMATION	
Package	PowerPAK [®] 1212-8SLW
Lead (Pb)-free and halogen-free	SQS120ELNW (for detailed order number please see www.vishay.com/doc?79771)

ABSOLUTE MAXIMUM RATINGS ($T_C = 25$ °C, unless otherwise noted)			
PARAMETER	SYMBOL	LIMIT	UNIT
Drain-source voltage	V_{DS}	30	V
Gate-source voltage	V_{GS}	± 20	
Continuous drain current ^e	I_D	$T_C = 25$ °C	192
		$T_C = 125$ °C	110
Continuous source current (diode conduction) ^e	I_S	108	A
Pulsed drain current ^{a, e}	I_{DM}	415	
Single pulse avalanche current	I_{AS}	L = 0.1 mH	33
Single pulse avalanche energy			E_{AS}
Maximum power dissipation ^{a, e}	P_D	$T_C = 25$ °C	119
		$T_C = 125$ °C	39
Operating junction and storage temperature range	T_J, T_{stg}	-55 to +175	°C
Soldering recommendations (peak temperature) ^c		260	

THERMAL RESISTANCE RATINGS			
PARAMETER	SYMBOL	LIMIT	UNIT
Junction-to-ambient	R_{thJA}	54	°C/W
Junction-to-case (drain) ^d			

Notes

- Pulse test; pulse width ≤ 300 μ s, duty cycle ≤ 2 %
- When mounted on 1" square PCB (FR4 material)
- See solder profile (www.vishay.com/doc?73257). A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- As per on JESD51-14
- Values based on R_{thJC} and T_C of 25 °C. Actual values achievable will be dependent on the thermal characteristics of the complete system



SPECIFICATIONS (T _C = 25 °C, unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static						
Drain-source breakdown voltage	V _{DS}	V _{GS} = 0, I _D = 250 μA	30	-	-	V
Gate-source threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 μA	1.5	2.0	2.5	
Gate-source leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 20 V	-	-	± 100	nA
Zero gate voltage drain current	I _{DSS}	V _{GS} = 0 V, V _{DS} = 30 V	-	-	1	μA
		V _{GS} = 0 V, V _{DS} = 30 V, T _J = 125 °C	-	-	50	
		V _{GS} = 0 V, V _{DS} = 30 V, T _J = 175 °C	-	-	150	
On-state drain current ^a	I _{D(on)}	V _{GS} = 10 V, V _{DS} ≥ 5 V	20	-	-	A
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 10 A	-	0.0022	0.0028	Ω
		V _{GS} = 10 V, I _D = 10 A	-	0.0015	0.0018	
		V _{GS} = 10 V, I _D = 10 A, T _J = 125 °C	-	-	0.0028	
		V _{GS} = 10 V, I _D = 10 A, T _J = 175 °C	-	-	0.0033	
Forward transconductance ^b	g _{fs}	V _{DS} = 15 V, I _D = 60 A	-	202	-	S
Dynamic ^b						
Input capacitance	C _{iSS}	V _{GS} = 0 V, V _{DS} = 25 V, f = 1 MHz	-	3278	4590	pF
Output capacitance	C _{oss}		-	1247	1746	
Reverse transfer capacitance	C _{rSS}		-	67	94	
Total gate charge ^c	Q _g	V _{GS} = 10 V, V _{DS} = 15 V, I _D = 4 A	-	59	88	nC
Gate-source charge ^c	Q _{gs}		-	10	-	
Gate-drain charge ^c	Q _{gd}		-	10	-	
Gate resistance	R _g	f = 1 MHz	0.6	1.4	2.4	Ω
Turn-on delay time ^c	t _{d(on)}	V _{DD} = 15 V, R _L = 6 Ω, I _D ≅ 2.5 A, V _{GEN} = 10 V, R _g = 1 Ω	-	13	21	ns
Rise time ^c	t _r		-	6	9	
Turn-off delay time ^c	t _{d(off)}		-	34	51	
Fall time ^c	t _f		-	15	23	
Source-Drain Diode Ratings and Characteristic ^b						
Pulsed current ^a	I _{SM}		-	-	350	A
Forward voltage	V _{SD}	I _F = 10 A, V _{GS} = 0 V	-	0.82	1.1	V
Body diode reverse recovery time	t _{rr}	V _{DD} = 24 V, I _{FM} = 3.5 A, di/dt = 100 A/μs, R = 10 Ω, L = 0.1 mH, pulse width = 2 μs	-	40	80	ns
Body diode reverse recovery charge	Q _{rr}		-	41	81	nC
Reverse recovery fall time	t _a		-	21	-	ns
Reverse recovery rise time	t _b		-	19	-	
Body diode peak reverse recovery current	I _{RM(REC)}			-	-1.7	-

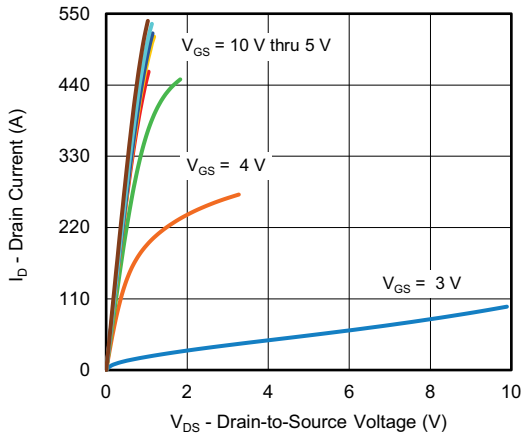
Notes

- a. Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2 %
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

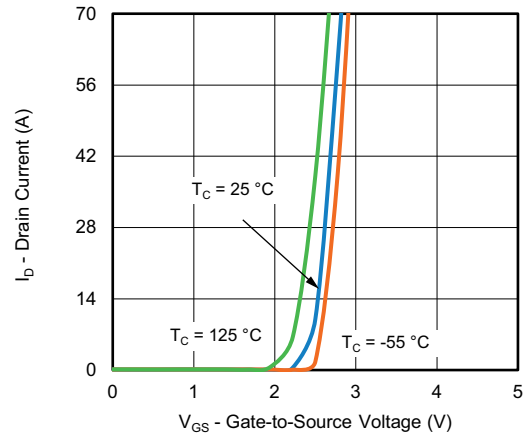
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



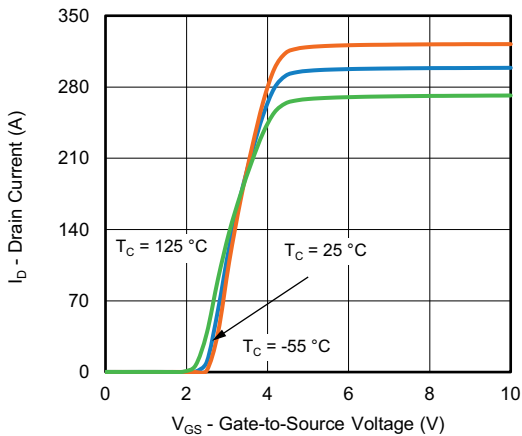
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



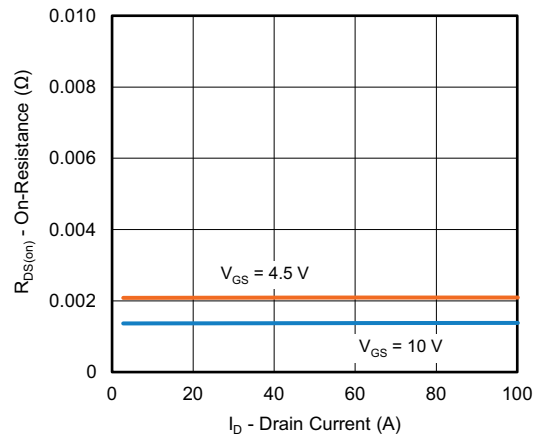
Output Characteristics



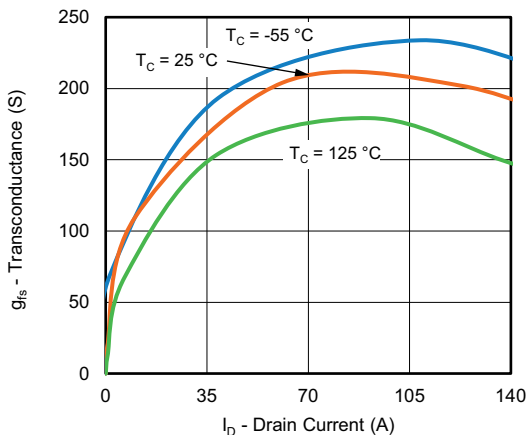
Transfer Characteristics



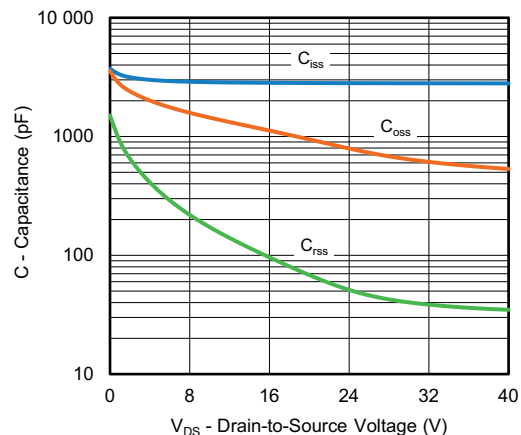
Transfer Characteristics



On-Resistance vs. Drain Current



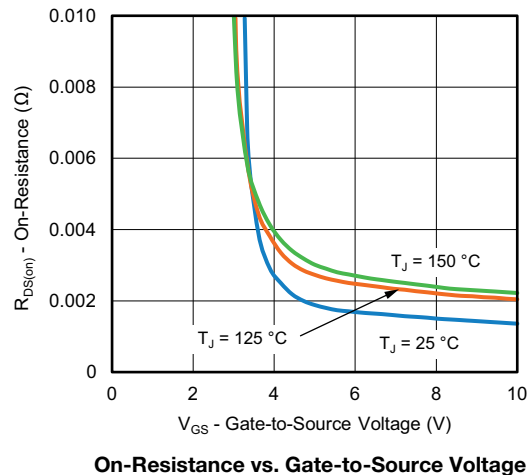
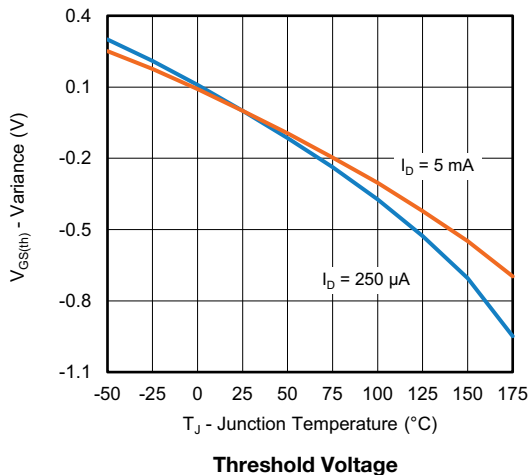
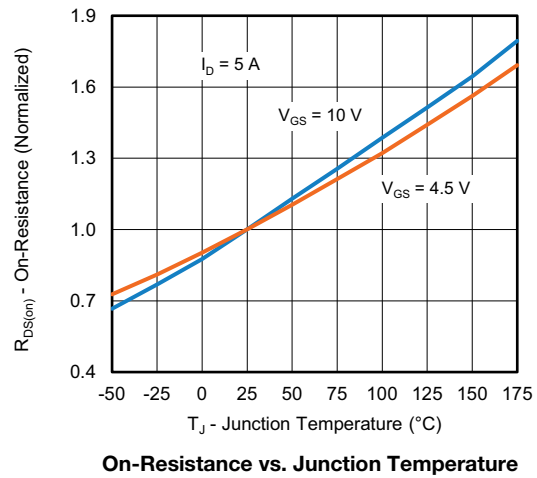
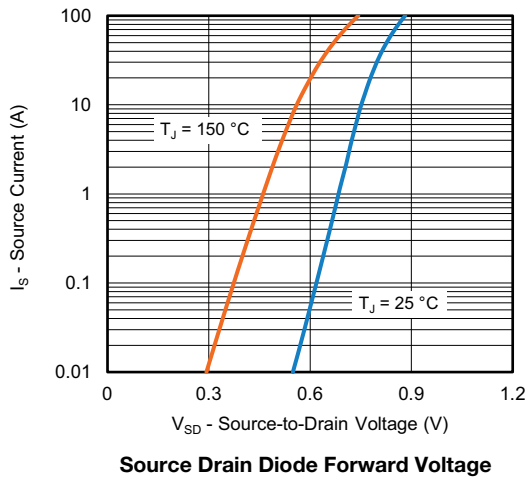
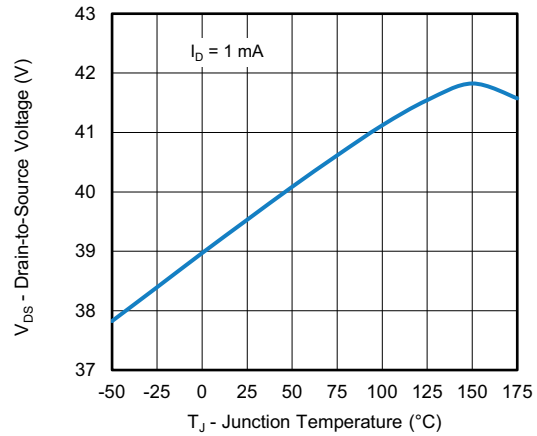
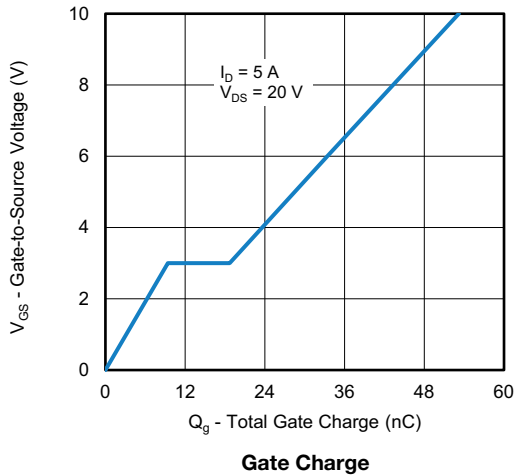
Transconductance



Capacitance

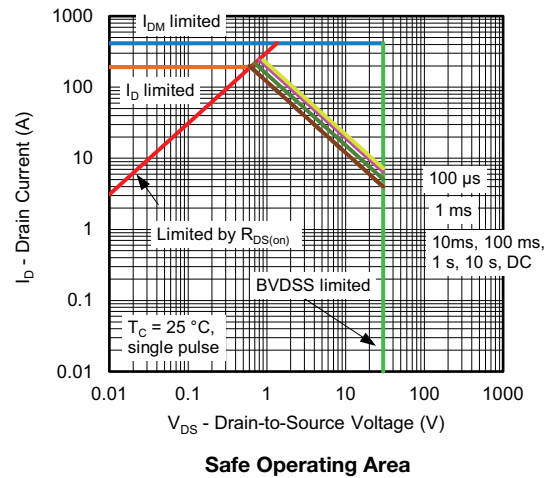


TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



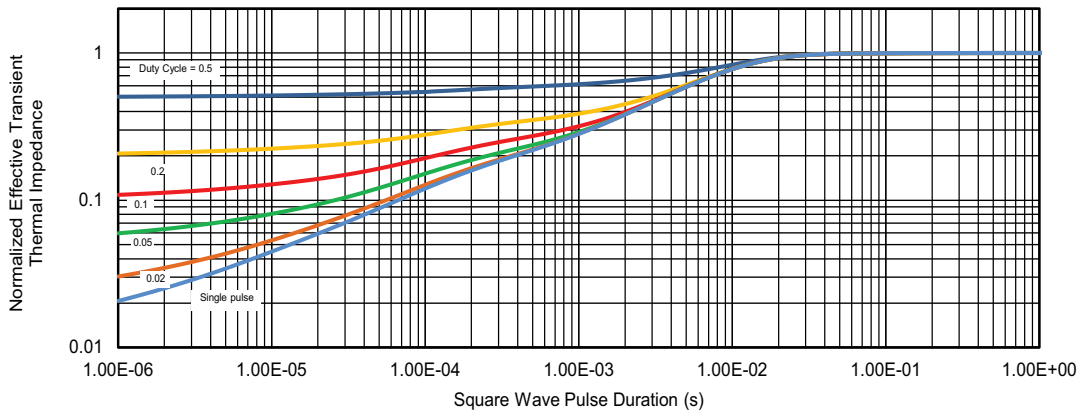


THERMAL RATINGS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)

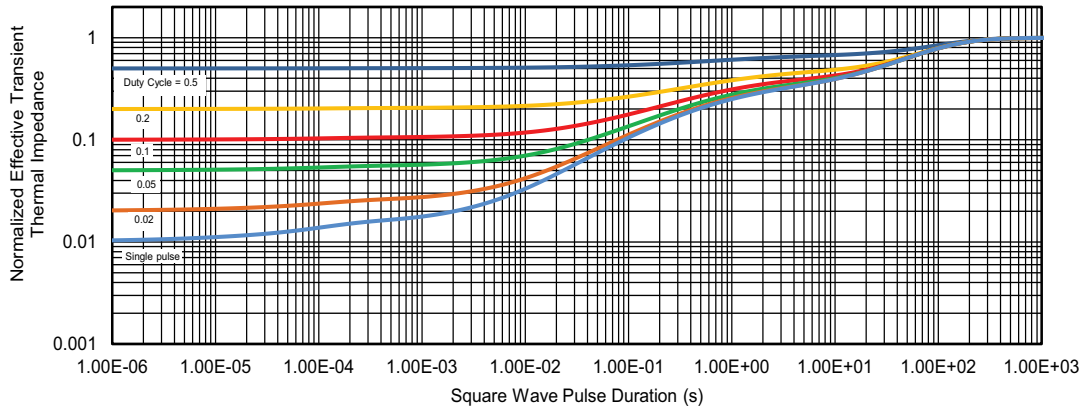


Note

- a. $V_{GS} >$ minimum V_{GS} at which $R_{DS(on)}$ is specified



Normalized Thermal Transient Impedance, Junction-to-Case



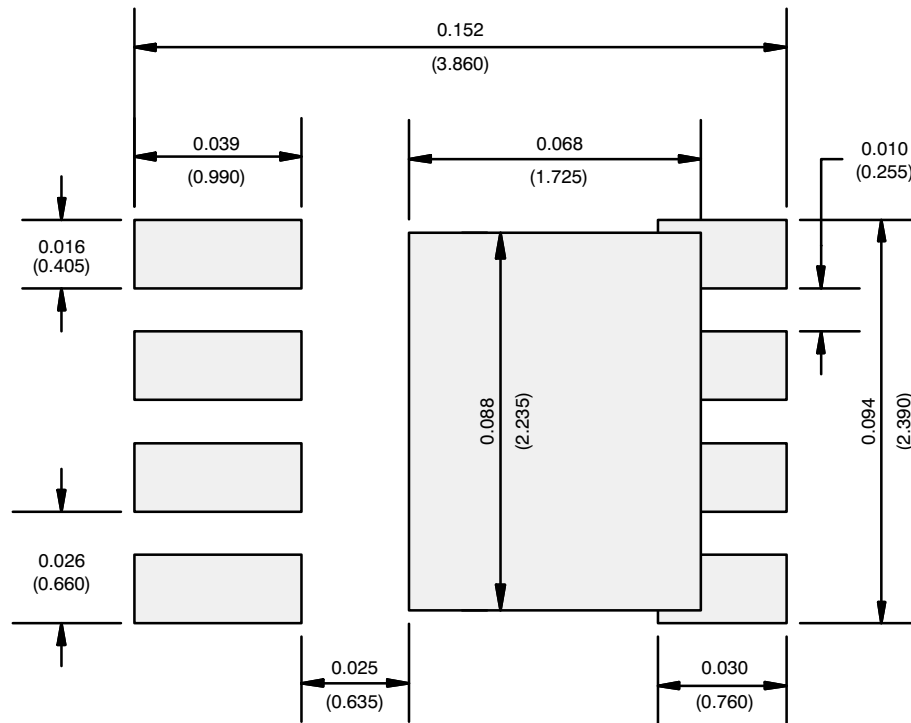
Normalized Thermal Transient Impedance, Junction-to-Ambient

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)
- are given for general guidelines only to enable the user to get a “ball park” indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

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RECOMMENDED MINIMUM PADS FOR PowerPAK® 1212-8 Single



Recommended Minimum Pads
Dimensions in Inches/(mm)

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